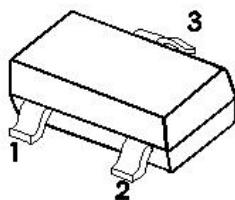


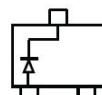
SOT-23 贴片塑封开关二极管
SOT-23 Plastic-Encapsulate Switching Diode

特征 Features**SOT-23**

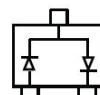
- 大电流承受能力。High Current Capability
- 正向压降低。Low Forward Voltage Drop
- 开关速度快。Extremely Fast Switching Speed

机械数据 Mechanical Data

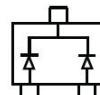
- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any



BAS70 Marking: 73



BAS70-04 Marking: 74



BAS70-05 Marking: 75



BAS70-06 Marking: 76

极限值和温度特性(TA = 25°C 除非另有规定)

Maximum Ratings & Thermal Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

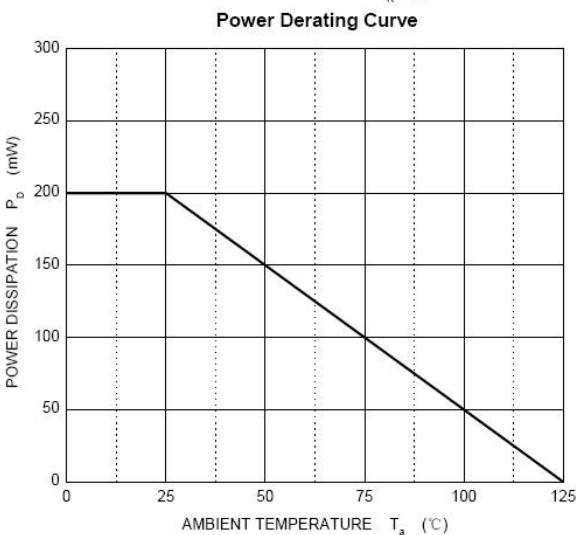
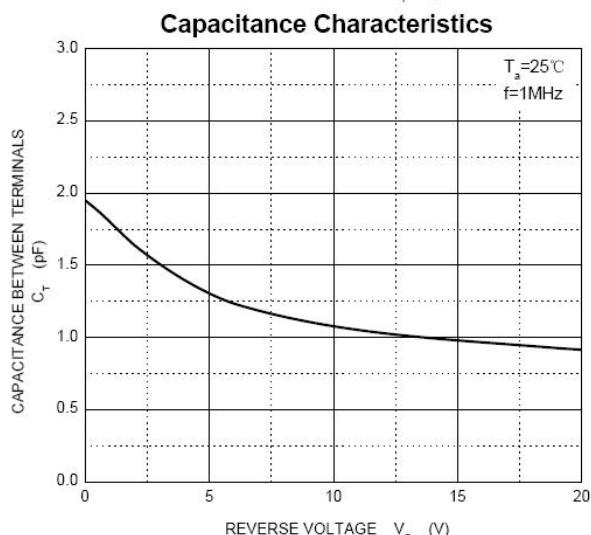
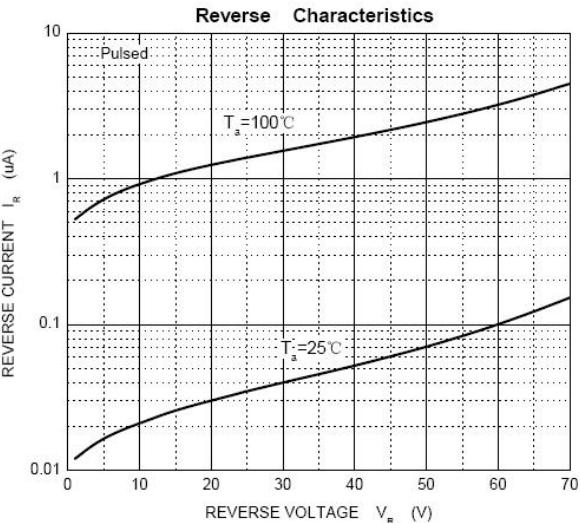
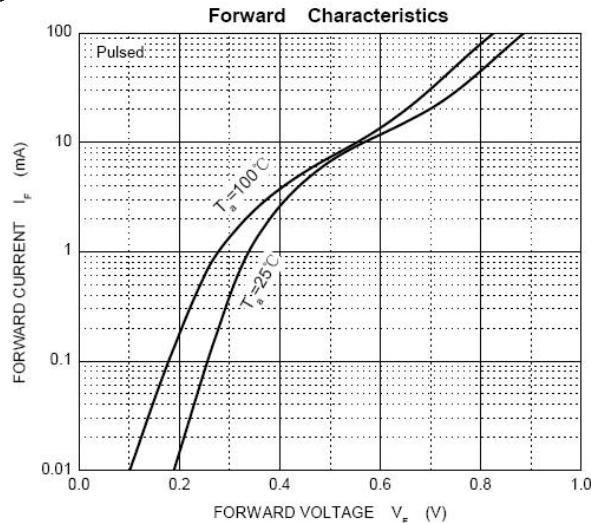
参数 Parameters	符号 Symbol	界限 Limit	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V _{RRM}	70	V
最大直流阻断电压 Maximum DC blocking voltage	V _{DC}	70	V
最大正向平均整流电流 Maximum average forward rectified current	I _{FM}	100	mA
典型热阻 Typical thermal resistance	R _{θJA}	500	°C/W
功率消耗 Power Dissipation	P _D	200	mW
结温 Junction Temperature	T _J	125	°C
存储温度 Storage temperature range	T _{STG}	-50-+150	°C

电特性 (TA = 25°C 除非另有规定)

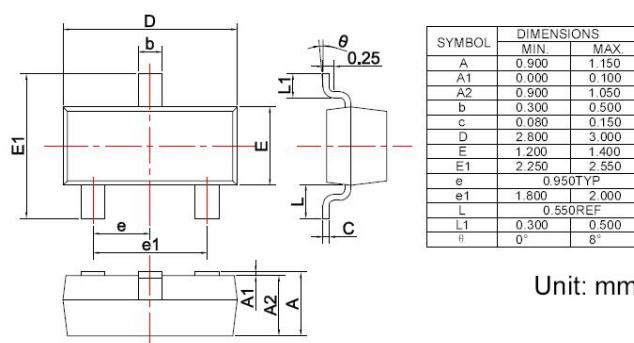
Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified).

参数 Parameters	符号 Symbol	测试条件 Test conditions	Min	Typ	Max	单位 Unit
最大正向电压 Maximum forward voltage	V _{F1}	IF = 1mA			410	mV
	V _{F2}	IF = 15mA			1000	
最大反向电压 Maximum reverse breakdown voltage	V _R	I _R =10uA	70			V
最大反向电流 Maximum reverse current	I _R	V _R =50V			100	nA
典型结电容 Type junction capacitance	C _D	VR = 0V, f = 1MHz			2	pF
反向恢复时间 Reverse Recovery time	t _{rr}	IF=IR=10mA I _{rr} =1XIR, R _L =100 Ω			5	ns

Typical Characteristics

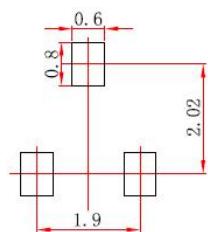


SOT-23 PACKAGE OUTLINE Plastic surface mounted package



Unit: mm

焊盘设计参考Precautions: PCB Design(Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs)



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.